10/677,311

FORM PTO 1449 (*modified*)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT(S)
(Use several sheets if necessary)

October 3, 2003

ATTY DOCKET NO.	APPLICATION NO.
03500.016340.1	UNASSIGNED (Cont. of 10/112,748)
APPLICANT: FUMIHIRO INUI	
FILING DATE: October 3, 2003	GROUP: 2818 Unassigned

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
JM		5,831,920	11/03/98	Chen, et al.	365	225.5	
JM		5,699,293	12/06/97	Tehrani, et al.	365	158	
JM		5,640,343	06/1997	Gallagher, et al.	365	171	
JM		6,055,178	04/2000	Naji	365	158	
JM		6,504,752	01/2003	Ito	365	158	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT

OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)

JM		Magneto-Resistive IC Memory Limitations and Architecture Implications, Roy E. Scheu rlein (pages 47 to 50), 1998 Int'l. Nonvolatile Memory Technology Conference.
JM		Spin-Valve-Like Ferromagnetic Tunnel Junction, Kazuo Kobayashi, et al. (Pages 11 to 17) (with English translation), November 5, 1999.

EXAMINER: SON MAI — DATE CONSIDERED: 07-15-04

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Sheet 1 of 1

CPW\gmc

DC_MAIN 144744v1